



DEC 2 6 2002 **TECH CENTER 1600/2900**

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Plateau Ic_{so} = 7.7 \pm 0.3 μ M (Hill 1.47) Peak IC₅₀ = $20.1 \pm 2.8 \, \mu M$ (Hill 1.42)

5 MRZ 2/633 on N1E-115 Cells MRZ 2/633 Concentration (µM) - Plateau Peak 8 **\$** 2 8 % Control 5HT-Induced Current

감 10µМ 본 250 pA MRZ 2/633 5 sec **З**µМ FF 7 Mid Mid 구· 감

FIG. 1B

FIG. 1A

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